











LM567, LM567C

SNOSBQ4E -MAY 1999-REVISED DECEMBER 2014

LM567x Tone Decoder

Features

- 20 to 1 Frequency Range With an External
- Logic Compatible Output With 100-mA Current Sinking Capability
- Bandwidth Adjustable From 0 to 14%
- High Rejection of Out of Band Signals and Noise
- Immunity to False Signals
- Highly Stable Center Frequency
- Center Frequency Adjustable from 0.01 Hz to 500 kHz

Applications

- **Touch Tone Decoding**
- **Precision Oscillator**
- Frequency Monitoring and Control
- Wide Band FSK Demodulation
- Ultrasonic Controls
- Carrier Current Remote Controls
- Communications Paging Decoders

3 Description

The LM567 and LM567C are general purpose tone decoders designed to provide a saturated transistor switch to ground when an input signal is present within the passband. The circuit consists of an I and Q detector driven by a voltage controlled oscillator which determines the center frequency of the External components are independently set center frequency, bandwidth and output delay.

Device Information⁽¹⁾

| PART NUMBER | PACKAGE | BODY SIZE (NOM) | |
|-------------|----------|-------------------|--|
| LM567C | SOIC (8) | 4.90 mm × 3.91 mm | |
| LIVISO/C | PDIP (8) | 9.81 mm × 6.35 mm | |

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Simplified Diagram

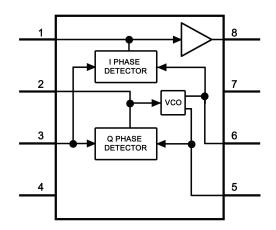




Table of Contents

| 1 | Features 1 | | 10.2 Functional Block Diagram | |
|----|--|----|--------------------------------------|----|
| - | | | | |
| 2 | Applications 1 | | 10.3 Feature Description | |
| 3 | Description 1 | | 10.4 Device Functional Modes | |
| 4 | Simplified Diagram 1 | 11 | Application and Implementation | |
| 5 | Revision History2 | | 11.1 Application Information | 13 |
| 6 | Device Comparison Table | | 11.2 Typical Applications | 13 |
| 7 | Pin Configuration and Functions | 12 | Power Supply Recommendations | 19 |
| 8 | Specifications | 13 | Layout | 19 |
| 0 | • | | 13.1 Layout Guidelines | 19 |
| | 8.1 Absolute Maximum Ratings | | 13.2 Layout Example | |
| | 8.2 Recommended Operating Conditions 4 | 14 | Device and Documentation Support | |
| | 8.3 Thermal Information 4 | | | |
| | 8.4 Electrical Characteristics 5 | | 14.1 Related Links | |
| | 8.5 Typical Characteristics | | 14.2 Trademarks | 20 |
| 9 | Parameter Measurement Information 8 | | 14.3 Electrostatic Discharge Caution | 20 |
| _ | | | 14.4 Glossary | 2 |
| 10 | Detailed Description 8 | 15 | Mechanical, Packaging, and Orderable | |
| | 10.1 Overview | 13 | Information | 2 |

5 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision D (March 2013) to Revision E

Page

Added Pin Configuration and Functions section, ESD Ratings table, Feature Description section, Device Functional
Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device
and Documentation Support section, and Mechanical, Packaging, and Orderable Information section

Changes from Revision C (March 2013) to Revision D

Page

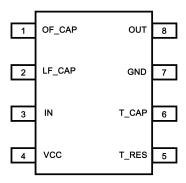


6 Device Comparison Table

| DEVICE NAME | DESCRIPTION | | | |
|---------------|--|--|--|--|
| LM567, LM567C | General Purpose Tone Decoder | | | |
| LMC567 | Same as LM567C, but lower power supply current consumption and double oscillator frequency | | | |

7 Pin Configuration and Functions

8-Pin PDIP (P) and SOIC (D) Package Top View



Pin Functions

| PIN | | TVDE | DESCRIPTION | | |
|--------|-----|------|---|--|--|
| NAME | NO. | TYPE | DESCRIPTION | | |
| GND | 7 | Р | Circuit ground. | | |
| IN | 3 | I | Device input. | | |
| LF_CAP | 2 | I | Loop filter capacitor pin (LPF of the PLL). | | |
| OUT | 8 | 0 | Device output. | | |
| OF_CAP | 1 | I | Output filter capacitor pin. | | |
| T_CAP | 5 | 1 | Timing capacitor connection pin. | | |
| T_RES | 6 | I | Timing resistor connection pin. | | |
| VCC | 4 | Р | Voltage supply pin. | | |

Product Folder Links: LM567 LM567C



8 Specifications

8.1 Absolute Maximum Ratings (1)(2)(3)

| | | | MIN | MAX | UNIT |
|---|------------------|--------------------|-----|----------------------|------|
| Supply Voltage Pin | | | | 9 | V |
| Power Dissipation ⁽⁴⁾ | | | | 1100 | mW |
| V ₈ | | | | 15 | V |
| V ₃ | | | | -10 | V |
| V_3 | | | | V ₄ + 0.5 | V |
| | LM567CM, LM567CN | | 0 | 70 | °C |
| On anating Tagana antique Dagana | PDIP Package | Soldering (10 s) | | 260 | °C |
| Operating Temperature Range Vapor Phase (60 s | | Vapor Phase (60 s) | | 215 | °C |
| | SOIC Package | Infrared (15 s) | | 220 | °C |
| Storage temperature range, T _{stq} | | | | 150 | °C |

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Recommended Operating Conditions indicate conditions for which the device is functional, but do not ensure specific performance limits. Electrical Characteristics state DC and AC electrical specifications under particular test conditions which ensure specific performance limits. This assumes that the device is within the Recommended Operating Conditions. Specifications are not ensured for parameters where no limit is given, however, the typical value is a good indication of device performance.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.
- (3) See http://www.ti.com for other methods of soldering surface mount devices.
- (4) The maximum junction temperature of the LM567 and LM567C is 150°C. For operating at elevated temperatures, devices in the DIP package must be derated based on a thermal resistance of 110°C/W, junction to ambient. For the SOIC package, the device must be derated based on a thermal resistance of 160°C/W, junction to ambient.

8.2 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | | MIN | MAX | UNIT |
|-----------------|-----------------------------|------|-----|------|
| V _{CC} | Supply Voltage | 3.5 | 8.5 | V |
| V _{IN} | Input Voltage Level | -8.5 | 8.5 | V |
| T _A | Operating Temperature Range | -20 | 120 | °C |

8.3 Thermal Information

| | | LMS | LM567C | | |
|----------------------|--|-------|--------|------|--|
| | THERMAL METRIC(1) | | Р | UNIT | |
| | | 8 P | INS | | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 107.5 | 53.0 | | |
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance | 54.6 | 42.3 | | |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 47.5 | 30.2 | °C/W | |
| Ψ_{JT} | Junction-to-top characterization parameter | 10.0 | 19.6 | | |
| ΨЈВ | Junction-to-board characterization parameter | 47.0 | 30.1 | | |

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

Submit Documentation Feedback



8.4 Electrical Characteristics

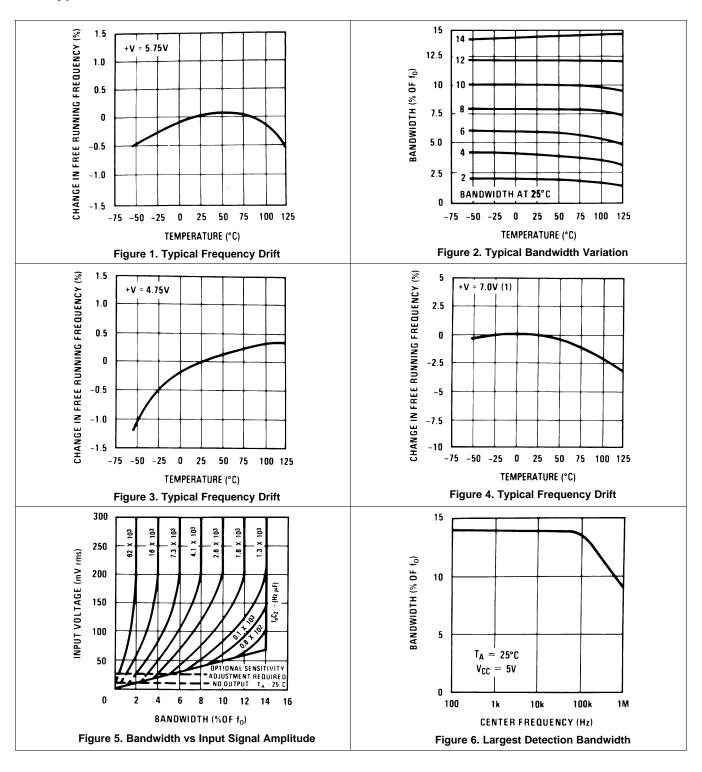
AC Test Circuit, $T_A = 25$ °C, $V^+ = 5 V$

| DADAMETED | TEST CONDITIONS | | LM567 | | LM567C/LM567CM | | | UNIT |
|--|---|------|---------------------|------------|----------------|---------------------|------------|---------------------|
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | MIN | TYP | MAX | UNII |
| Power Supply Voltage Range | | 4.75 | 5.0 | 9.0 | 4.75 | 5.0 | 9.0 | V |
| Power Supply Current Quiescent | R _L = 20k | | 6 | 8 | | 7 | 10 | mA |
| Power Supply Current Activated | R _L = 20k | | 11 | 13 | | 12 | 15 | mA |
| Input Resistance | | 18 | 20 | | 15 | 20 | | kΩ |
| Smallest Detectable Input Voltage | $I_L = 100 \text{ mA}, f_i = f_0$ | | 20 | 25 | | 20 | 25 | mVrms |
| Largest No Output Input Voltage | $I_C = 100 \text{ mA}, f_i = f_o$ | 10 | 15 | | 10 | 15 | | mVrms |
| Largest Simultaneous Outband Signal to Inband Signal Ratio | | | 6 | | | 6 | | dB |
| Minimum Input Signal to Wideband Noise Ratio | B _n = 140 kHz | | -6 | | | -6 | | dB |
| Largest Detection Bandwidth | | 12 | 14 | 16 | 10 | 14 | 18 | % of f _o |
| Largest Detection Bandwidth Skew | | | 1 | 2 | | 2 | 3 | % of f _o |
| Largest Detection Bandwidth Variation with Temperature | | | ±0.1 | | | ±0.1 | | %/°C |
| Largest Detection Bandwidth Variation with Supply Voltage | 4.75 – 6.75 V | | ±1 | ±2 | | ±1 | ±5 | %V |
| Highest Center Frequency | | 100 | 500 | | 100 | 500 | | kHz |
| Center Frequency Stability (4.75 – 5.75 V) | 0 < T _A < 70 -55 < T _A < +125 | | 35 ± 60 35 ± 140 | | | 35 ± 60 35 ± 140 | | ppm/°C ppm/°C |
| Center Frequency Shift with Supply Voltage | 4.75 V – 6.75 V 4.75 V – 9 V | | 0.5 | 1.0 2.0 | | 0.4 | 2.0 2.0 | %/V %/V |
| Fastest ON-OFF Cycling Rate | | | f _o /20 | | | f _o /20 | | |
| Output Leakage Current | V ₈ = 15 V | | 0.01 | 25 | | 0.01 | 25 | μΑ |
| Output Saturation Voltage | e _i = 25 mV, I ₈ = 30 mA e _i = 25 mV, I ₈ = 100 mA | | 0.2 0.6 | 0.4 1.0 | | 0.2 0.6 | 0.4 1.0 | V |
| Output Fall Time | | | 30 | | | 30 | | ns |
| Output Rise Time | | | 150 | | | 150 | | ns |

Submit Documentation Feedback



8.5 Typical Characteristics





Typical Characteristics (continued)

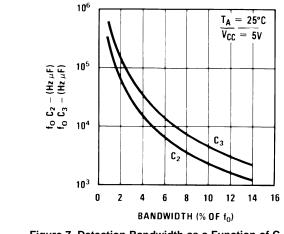
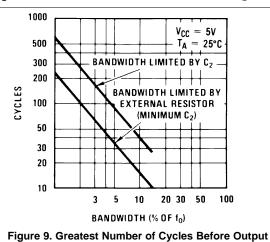


Figure 7. Detection Bandwidth as a Function of C2 and C3



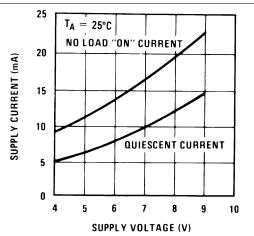


Figure 8. Typical Supply Current vs Supply Voltage

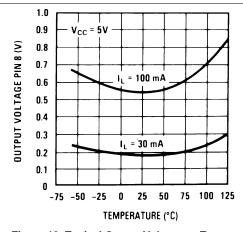


Figure 10. Typical Output Voltage vs Temperature



9 Parameter Measurement Information

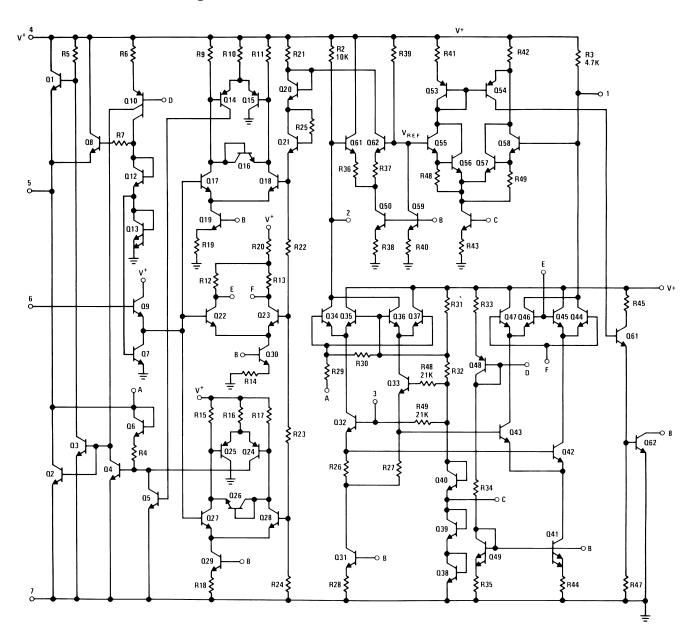
All parameters are measured according to the conditions described in the Specifications section.

10 Detailed Description

10.1 Overview

The LM567C is a general purpose tone decoder. The circuit consists of I and Q detectors driven by a voltage controlled oscillator which determines the center frequency of the decoder. This device is designed to provide a transistor switch to ground output when the input signal frequency matches the center frequency pass band. Center frequency is set by an external timing circuit composed by a capacitor and a resistor. Bandwidth and output delay are set by external capacitors.

10.2 Functional Block Diagram



Submit Documentation Feedback

Copyright © 1999–2014, Texas Instruments Incorporated

(1)



10.3 Feature Description

10.3.1 Center Frequency

The center frequency of the LM567 tone decoder is equal to the free running frequency of the voltage controlled oscillator. In order to set this frequency, external components should be placed externally. The component values are given by:

$$f_0 \approx \frac{1.1}{R_1 C_1}$$

where

10.3.2 Output Filter

To eliminate undesired signals that could trigger the output stage, a post detection filter is featured in the LM567C. This filter consists of an internal resistor $(4.7K-\Omega)$ and an external capacitor. Although typically external capacitor value is not critical, it is recommended to be at least twice the value of the loop filter capacitor. If the output filter capacitor value is too large, the turn-on and turn off-time of the output will present a delay until the voltage across this capacitor reaches the threshold level.

10.3.3 Loop Filter

The phase locked loop (PLL) included in the LM567 has a pin for connecting the low pass loop filter capacitor. The selection of the capacitor for the filter depends on the desired bandwidth. The device bandwidth selection is different according to the input voltage level. Refer to the *Operation With V_i* < $200m - V_{RMS}$ section and the *Operation With V_i* > $200m - V_{RMS}$ section for more information about the loop filter capacitor selection.

10.3.4 Logic Output

The LM567 is designed to provide a transistor switch to ground output when the input signal frequency matches the center frequency pass band. The logic output is an open collector power transistor that requires an external load resistor that is used to regulate the output current level.

10.3.5 Die Characteristics

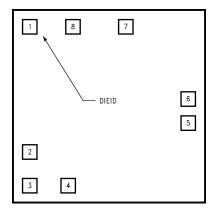


Figure 11. Die Layout (C - Step)

Submit Documentation Feedback



Feature Description (continued)

Table 1. Die and Wafer Characteristics

| Fabrication Attributes | | General Die Information | | | | |
|---|---------------|-----------------------------|------------------------------|--|--|--|
| Physical Die Identification LM567C | | Bond Pad Opening Size (min) | 91µm x 91µm | | | |
| Die Step C | | Bond Pad Metalization | 0.5% COPPER_BAL. ALUMINUM | | | |
| Physical Attributes | | Passivation | VOM NITRIDE | | | |
| Wafer Diameter | 150mm | Back Side Metal | BARE BACK | | | |
| Dise Size (Drawn) 1600µm x 1626µm 63.0mils x 64.0mils | | Back Side Connection | Floating | | | |
| Thickness | 406µm Nominal | | · | | | |
| Min Pitch 198µm Nominal | | | | | | |
| Special Assembly Requirements: | | | | | | |
| Note: Actual die size is rounded to the neares | t micron. | | | | | |

| Die Bond Pad Coordinate Locations (C - Step) | | | | | | |
|--|----------------|----------------------|---------------------|------------------|------------|-----|
| | (Referenced to | die center, coordina | ates in µm) NC = No | Connection, N.U. | = Not Used | |
| OLONIAL NAME | DAD#AUMDED | X/Y COO | RDINATES | | PAD SIZE | |
| SIGNAL NAME | PAD# NUMBER | Х | Υ | Х | | Y |
| OUTPUT FILTER | 1 | -673 | 686 | 91 | х | 91 |
| LOOP FILTER | 2 | -673 | -419 | 91 | х | 91 |
| INPUT | 3 | -673 | -686 | 91 | х | 91 |
| V+ | 4 | -356 | -686 | 91 | х | 91 |
| TIMING RES | 5 | 673 | -122 | 91 | х | 91 |
| TIMING CAP | 6 | 673 | 76 | 91 | х | 91 |
| GND | 7 | 178 | 686 | 117 | х | 91 |
| OUTPUT | 8 | -318 | 679 | 117 | х | 104 |

10.4 Device Functional Modes

10.4.1 Operation With $V_i < 200m - V_{RMS}$

When the input signal is below a threshold voltage, typically 200m-VRMS, the bandwidth of the detection band should be calculated .

BW = 1070
$$\sqrt{\frac{V_i}{f_o C_2}}$$
 in % of f_o

where

- V_i = Input voltage (volts rms), $V_i \le 200 \text{mV}$
- C₂ = Capacitance at Pin 2(μF)

Submit Documentation Feedback

Copyright © 1999–2014, Texas Instruments Incorporated



Device Functional Modes (continued)

10.4.2 Operation With $V_i > 200m - V_{RMS}$

For input voltages greater than 200m-VRMS, the bandwidth depends directly from the loop filter capacitance and free running frequency product. Bandwidth is represented as a percentage of the free running frequency, and according to the product of f0·C2, it can have a variation from 2 to 14%. Table 2 shows the approximate values for bandwidth in function of the product result.

Table 2. Detection Bandwidth in Function of fo x C2

| f _o × C ₂ (kHzμF) | Bandwidth (% of f _o) |
|---|----------------------------------|
| 62 | 2 |
| 16 | 4 |
| 7.3 | 6 |
| 4.1 | 8 |
| 2.6 | 10 |
| 1.8 | 12 |
| 1.3 | 14 |
| < 1.3 | 14 |

Submit Documentation Feedback

Product Folder Links: LM567 LM567C



11 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

11.1 Application Information

The LM567 tone decoder is a device capable of detecting if an input signal is inside a selectable range of detection. The device has an open collector transistor output, so an external resistor is required to achieve proper logic levels. When the input signal is inside the detection band, the device output will go to a LOW state. The internal VCO free running frequency establishes the detection band central frequency. An external RC filter is required to set this frequency. The bandwidth in which the device will detect the desired frequency depends on the capacitance of loop filter terminal. Typically a 1 μ F capacitor is connected to this pin. The device detection band has a different behavior for low and high input voltage levels. Refer to the *Operation With V_i* < 200m - V_{RMS} section and the *Operation With V_i* > 200m - V_{RMS} section for more information.

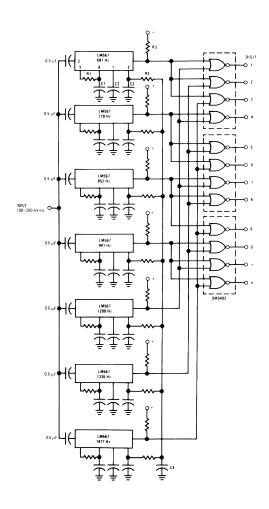
Submit Documentation Feedback

Copyright © 1999–2014, Texas Instruments Incorporated



11.2 Typical Applications

11.2.1 Touch-Tone Decoder



Component values (typ)

R1 6.8 to 15k

R2 4.7k

R3 20k

C1 0.10 mfd

C2 1.0 mfd 6V

C3 2.2 mfd 6V

C4 250 mfd 6V

Figure 12. Touch-Tone Decoder

11.2.1.1 Design Requirements

| PARAMETERS | VALUES |
|----------------------|-------------------------------------|
| Supply Voltage Range | 3.5 V to 8.5 V |
| Input Voltage Range | 20 mV _{RMS} to VCC + 0.5 |
| Input Frequency | 1 Hz to 500 kHz |
| Output Current | Max. 15 mA |

Product Folder Links: LM567 LM567C



11.2.1.2 Detailed Design Procedure

11.2.1.2.1 Timing Components

To calculate the timing components for an approximated desired central detection frequency (f_0) , the timing capacitor value (C_1) should be stated in order to calculate the timing resistor value (R_1) . Typically for most applications, a 0.1- μ F capacitor is used.

$$f_o \approx \frac{1.1}{R_1 C_1} \tag{2}$$

11.2.1.2.2 Bandwidth

Detection bandwidth is represented as a percentage of f0. It can be selected based on the input voltage levels (Vi). For Vi $< 200 \text{ mV}_{RMS}$,

BW = 1070
$$\sqrt{\frac{V_i}{f_o C_2}}$$
 in % of f_o (3)

For Vi > 200 mV_{RMS}, refer to Table 2 or Figure 5.

11.2.1.2.3 Output Filter

The output filter selection is made considering the capacitor value to be at least twice the Loop filter capacitor.

$$C_3 \ge 2C_2 \tag{4}$$

11.2.1.3 Application Curve

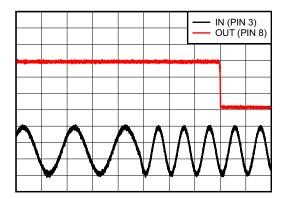


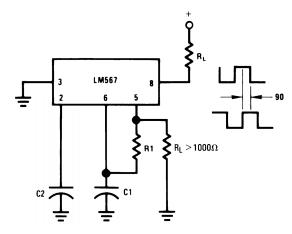
Figure 13. Frequency Detection

Submit Documentation Feedback

Copyright © 1999–2014, Texas Instruments Incorporated



11.2.2 Oscillator with Quadrature Output



Connect Pin 3 to 2.8V to Invert Output

Figure 14. Oscillator with Quadrature Output

11.2.2.1 Design Requirements

Refer to the previous *Design Requirements* section.

11.2.2.2 Detailed Design Procedure

Refer to the previous *Detailed Design Procedure* section.

11.2.2.3 Application Curve

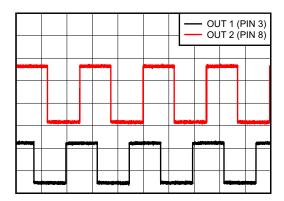


Figure 15. Quadrature Output



11.2.3 Oscillator with Double Frequency Output

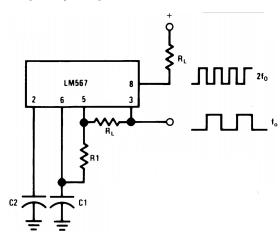


Figure 16. Oscillator with Double Frequency Output

11.2.3.1 Design Requirements

Refer to the previous Design Requirements section.

11.2.3.2 Detailed Design Procedure

Refer to the previous *Detailed Design Procedure* section.

11.2.3.3 Application Curve

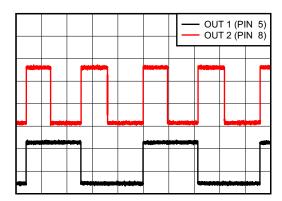


Figure 17. Double Frequency Output

Submit Documentation Feedback



11.2.4 Precision Oscillator Drive 100-mA Loads

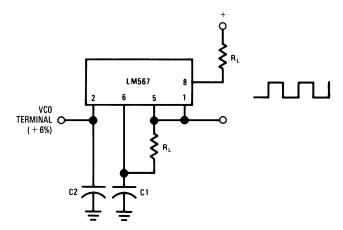


Figure 18. Precision Oscillator Drive 100-mA Loads

11.2.4.1 Design Requirements

Refer to the previous *Design Requirements* section.

11.2.4.2 Detailed Design Procedure

Refer to the previous *Detailed Design Procedure* section.

11.2.4.3 Application Curve

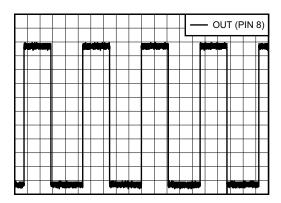
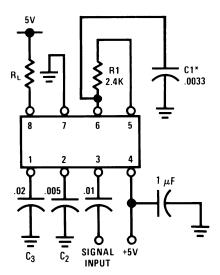


Figure 19. Output for 100-mA Load



11.2.5 AC Test Circuit



 f_i = 100 kHz + 5 V *Note: Adjust for f_o = 100 kHz.

11.2.5.1 Design Requirements

Refer to the previous Design Requirements section.

11.2.5.2 Detailed Design Procedure

Refer to the previous *Detailed Design Procedure* section.

11.2.5.3 Application Curve

Refer to the previous *Application Curve* section.

Submit Documentation Feedback



12 Power Supply Recommendations

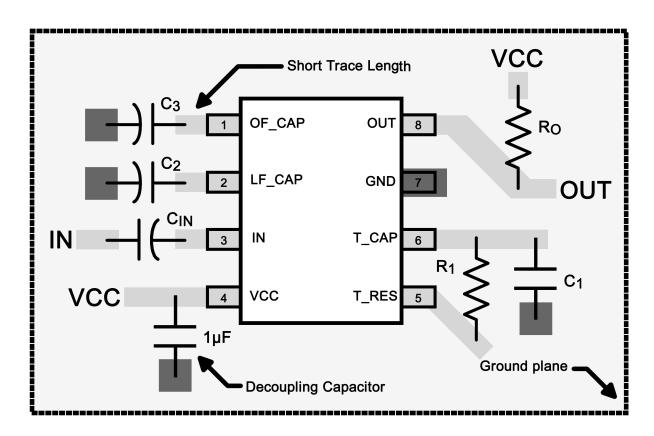
The LM567C is designed to operate with a power supply up to 9 V. It is recommended to have a well regulated power supply. As the operating frequency of the device could be very high for some applications, the decoupling of power supply becomes critical, so is required to place a proper decoupling capacitor as close as possible to VCC pin.

13 Layout

13.1 Layout Guidelines

The VCC pin of the LM567 should be decoupled to ground plane as the device can work with high switching speeds. The decoupling capacitor should be placed as close as possible to the device. Traces length for the timing and external filter components should be kept at minimum in order to avoid any possible interference from other close traces.

13.2 Layout Example



Top Layer Ground Pour

Pad toTop Layer Ground Pour

Top Layer Signal Traces

Figure 20. LM567 Layout Example



14 Device and Documentation Support

14.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 3. Related Links

| PARTS | PRODUCT FOLDER | SAMPLE & BUY | TECHNICAL DOCUMENTS | TOOLS & SOFTWARE | SUPPORT & COMMUNITY | |
|--------|----------------|--------------|---------------------|---------------------|---------------------|--|
| LM567 | Click here | Click here | Click here | Click here | Click here | |
| LM567C | Click here | Click here | Click here | Click here | Click here | |

14.2 Trademarks

All trademarks are the property of their respective owners.

14.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

14.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

15 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: LM567 LM567C



PACKAGE OPTION ADDENDUM



25-Feb-2015

PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package Drawing | | Package Qty | Eco Plan | Lead/Ball Finish (6) | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|----------|--------------|--------------------|---|----------------|----------------------------|----------------------|--------------------|--------------|-------------------------|---------|
| LM567CM | ACTIVE | SOIC | D | 8 | 95 | TBD | Call TI | Call TI | 0 to 70 | LM 567CM | Samples |
| LM567CM/NOPB | ACTIVE | SOIC | D | 8 | 95 | Green (RoHS & no Sb/Br) | CU SN | Level-1-260C-UNLIM | 0 to 70 | LM 567CM | Samples |
| LM567CMX/NOPB | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU SN | Level-1-260C-UNLIM | 0 to 70 | LM 567CM | Samples |
| LM567CN/NOPB | ACTIVE | PDIP | Р | 8 | 40 | Green (RoHS & no Sb/Br) | CU SN | Level-1-NA-UNLIM | 0 to 70 | LM 567CN | Samples |
| NE567V | OBSOLETI | E PDIP | Р | 8 | | TBD | Call TI | Call TI | 0 to 70 | LM 567CN | |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



PACKAGE OPTION ADDENDUM

25-Feb-2015

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 3-Oct-2014

TAPE AND REEL INFORMATION





| A0 | <u> </u> |
|----|---|
| B0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | | | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| LM567CMX/NOPB | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.5 | 5.4 | 2.0 | 8.0 | 12.0 | Q1 |

PACKAGE MATERIALS INFORMATION

www.ti.com 3-Oct-2014



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) | |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|--|
| LM567CMX/NOPB | SOIC | D | 8 | 2500 | 367.0 | 367.0 | 35.0 | |

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products Applications

Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive **Amplifiers** amplifier.ti.com Communications and Telecom www.ti.com/communications **Data Converters** dataconverter.ti.com Computers and Peripherals www.ti.com/computers **DLP® Products** www.dlp.com Consumer Electronics www.ti.com/consumer-apps DSP dsp.ti.com **Energy and Lighting** www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface interface.ti.com Medical www.ti.com/medical Logic Security www.ti.com/security logic.ti.com

Power Mgmt power.ti.com Space, Avionics and Defense www.ti.com/space-avionics-defense

Microcontrollers microcontroller.ti.com Video and Imaging www.ti.com/video

RFID www.ti-rfid.com

OMAP Applications Processors www.ti.com/omap TI E2E Community e2e.ti.com

Wireless Connectivity www.ti.com/wirelessconnectivity